

Features

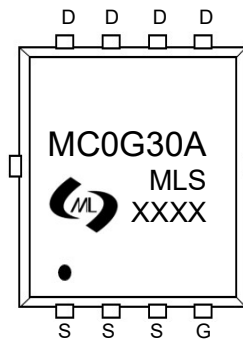
- High density cell design for ultra low $R_{DS(ON)}$
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

Product Summary

V_{DS}	$R_{DS(ON)}$ MAX	I_D MAX
60V	30mΩ@10V	30A
	40mΩ@4.5V	

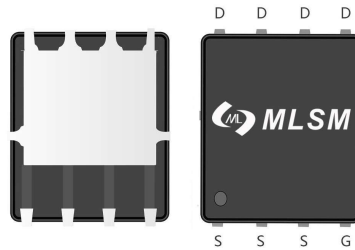
Application

- Power switching application

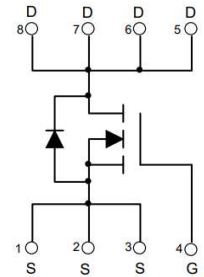


MC0G30A: Device code
XXXX: Code

Marking and pin assignment



PDFN5X6-8L view



Schematic diagram



Pb-Free



Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

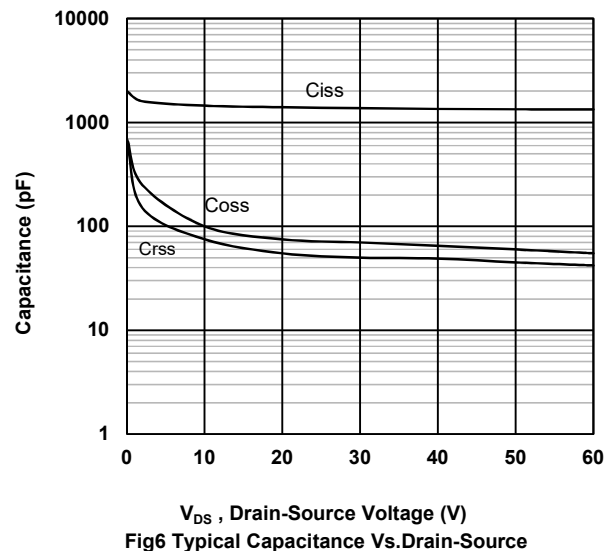
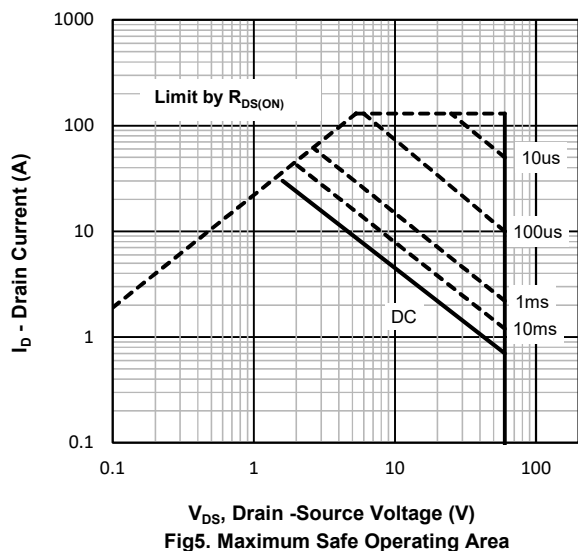
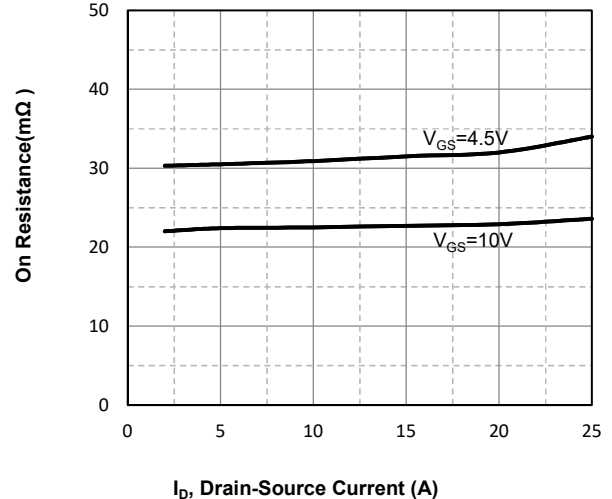
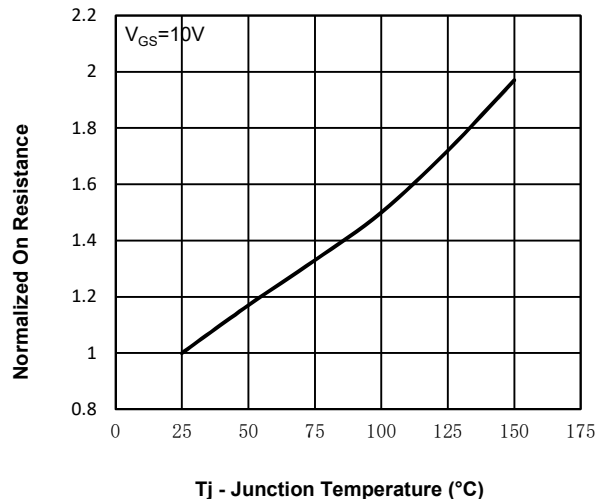
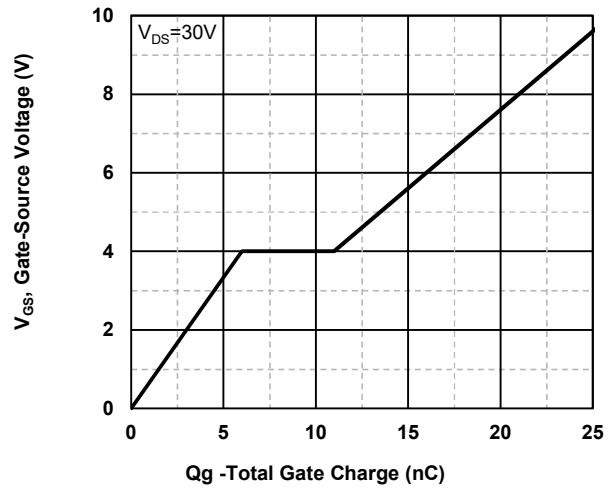
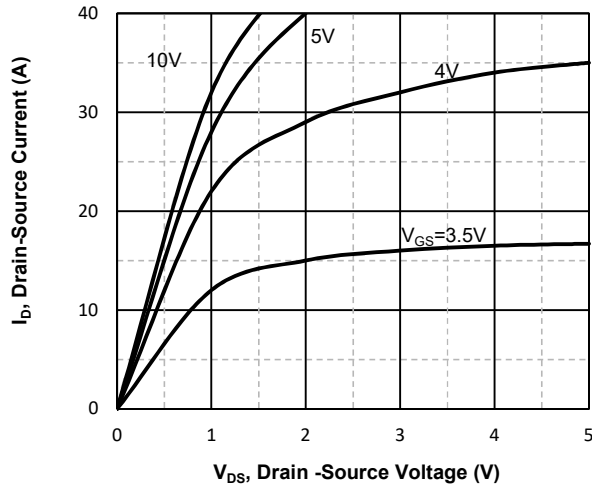
Symbol	Parameter		Rating	Unit
Common Ratings (TC=25°C Unless Otherwise Noted)				
V _{DS}	Drain-Source Breakdown Voltage		60	V
V _{GS}	Gate-Source Voltage		±20	V
T _J	Maximum Junction Temperature		150	°C
T _{STG}	Storage Temperature Range		-50 to 155	°C
I _S	Diode Continuous Forward Current	Tc=25°C	30	A
Mounted on Large Heat Sink				
I _{DM}	Pulse Drain Current Tested	Tc=25°C	130	A
I _D	Continuous Drain Current	Tc=25°C	30	A
P _D	Maximum Power Dissipation	Tc=25°C	35	W
R _{θJA}	Thermal Resistance Junction-Ambient		70	°C/W

Ordering Information (Example)

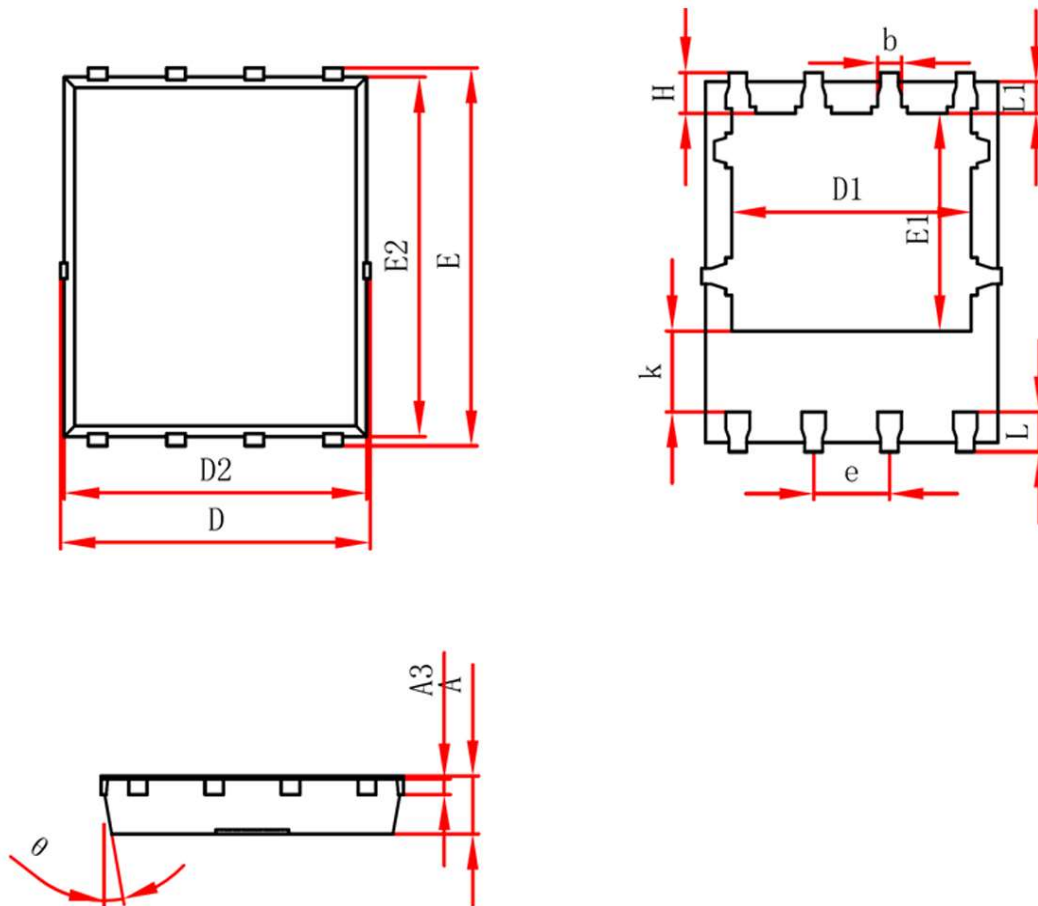
Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MC0G30A	PDFN5X6-8L	MC0G30A	5,000	10,000	70,000	13"reel

Electrical Characteristics (TJ=25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ TJ = 25°C (unless otherwise stated)						
BV(BR)DSS	Drain-Source Breakdown Voltage	VGS=0V, ID=250μA	60	--	--	V
IDSS	Zero Gate Voltage Drain Current	VDS=60V, VGS=0V	--	--	1	μA
IGSS	Gate-Body Leakage Current	VGS=±20V, VDS=0V	--	--	±100	nA
VGS(th)	Gate Threshold Voltage	VDS=VGS, ID=250μA	1.0	1.7	2.5	V
RDS(on)	Drain-Source On-State Resistance	VGS=10V, ID=20A	--	22	30	mΩ
		VGS=4.5V, ID=10A	--	30	40	mΩ
Dynamic Electrical Characteristics @ TJ = 25°C (unless otherwise stated)						
Ciss	Input Capacitance	VDS=30V, VGS=0V, f=1MHz	--	1050	--	pF
Coss	Output Capacitance		--	65	--	pF
CRSS	Reverse Transfer Capacitance		--	55	--	pF
Switching Characteristics						
Qg	Total Gate Charge	VDD=30V, ID=20A, VGS=10V	--	26	--	nC
Qgs	Gate Source Charge		--	5.7	--	nC
Qgd	Gate Drain Charge		--	5.2	--	nC
td(on)	Turn-on Delay Time	VDD=30V, ID=20A, VGS=10V, RG=3Ω	--	8.4	--	nS
tr	Turn-on Rise Time		--	8.5	--	nS
td(off)	Turn-Off Delay Time		--	36	--	nS
tf	Turn-Off Fall Time		--	5	--	nS
Source- Drain Diode Characteristics						
VSD	Forward on voltage	TJ=25°C, IS=20A	--	0.8	1.2	V

Typical Operating Characteristics



PDFN5X6-8L Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.950	1.050	0.035	0.039
A3	0.254REF.		0.010REF.	
D	4.950	5.050	0.196	0.200
E	5.950	6.050	0.235	0.239
D1	4.026	4.126	0.159	0.163
E1	3.510	3.610	0.139	0.143
D2	4.850	4.950	0.192	0.196
E2	5.700	5.800	0.225	0.229
k	1.190	1.390	0.047	0.055
b	0.300	0.400	0.012	0.016
e	1.270TYP.		0.050TYP.	
L	0.559	0.711	0.022	0.028
L1	0.424	0.576	0.017	0.023
H	0.574	0.726	0.023	0.029
θ	10°	12°	10°	12°